NSN 5961-01-019-2919

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Unitized Semiconductor Devices - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-019-2919 **Inclosure Material:** Metal **Overall Length:** 0.260 inches **Terminal Length:** 0.500 inches **Overall Height:** 0.760 inches **Overall Diameter:** Between 0.335 inches and 0.370 inches **Component Name And Quantity:** 2 transistor **Mounting Method: Terminal Terminal Circle Diameter:** Between 0.190 inches and 0.210 inches **Features Provided:** Burn in and hermetically sealed case **Semiconductor Material:** Silicon all transistor Voltage Rating In Volts Per Characteristic: 60.0 collector to base voltage, dc all transistor and 7.0 emitter to base voltage, instantaneous all transistor **Current Rating Per Characteristic:** 10.00 milliamperes source cutoff current all transistor **Power Rating Per Characteristic:** 400.0 milliwatts small-signal input power, common-collector all transistor **Special Features:** All transistor junction pattern arrangement: npn **Terminal Type And Quantity:** 6 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: